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Vishay Semiconductors

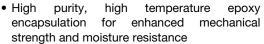
High Performance Schottky Rectifier, 2 x 15 A



PRIMARY CHARACTERISTICS								
I _{F(AV)}	2 x 15 A							
V_{R}	50 V, 60 V							
V _F at I _F	0.56 V							
I _{RM} max.	45 mA at 125 °C							
T _J max.	150 °C							
E _{AS}	13 mJ							
Package	3L TO-220AB							
Circuit configuration	Common cathode							

FEATURES

- 150 °C T_J operation
- Very low forward voltage drop
- High frequency operation





- Guard ring for enhanced ruggedness and long term reliability
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

This center tap Schottky rectifier has been optimized for very low forward voltage drop, with moderate leakage. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS								
SYMBOL	CHARACTERISTICS	VALUES	UNITS					
I _{F(AV)}	Rectangular waveform	30	Α					
V _{RRM}		50/60	V					
I _{FSM}	t _p = 5 μs sine	1000	Α					
V _F	15 A _{pk} , T _J = 125 °C (per leg)	0.56	V					
T _J	Range	-55 to +150	°C					

VOLTAGE RATINGS								
PARAMETER	SYMBOL	VS-30CTQ050-M3	VS-30CTQ060-M3	UNITS				
Maximum DC reverse voltage	V_R	50	60	V				
Maximum working peak reverse voltage	V_{RWM}	50	00	V				

ABSOLUTE MAXIMUM RATINGS									
PARAMETER	SYMBOL	TEST COND	VALUES	UNITS					
Maximum average forward per device		50 % duty cycle at T_C = 105 °C, rectangular waveform		30	•				
current, see fig. 5 per leg	I _{F(AV)}			15					
Maximum peak one cycle non-repetitive		5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated	1000	A				
surge current per leg, see fig. 7	IFSM	10 ms sine or 6 ms rect. pulse	V _{RRM} applied	260					
Non-repetitive avalanche energy per leg	E _{AS}	T _J = 25 °C, I _{AS} = 1.50 A, L = 11.5 mH		13	mJ				
Repetitive avalanche current per leg	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		1.50	Α				



VS-30CTQ050-M3, VS-30CTQ060-M3

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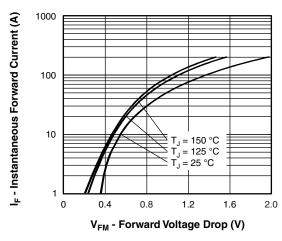
ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CO	TEST CONDITIONS					
		15 A	T _{.1} = 25 °C	0.62	V			
Maximum forward voltage drop per leg	V (1)	30 A	1J=25 C	0.82				
See fig. 1	V _{FM} ⁽¹⁾	15 A	T 105 °C	0.56				
		30 A	T _J = 125 °C	0.71				
Maximum reverse leakage current per leg	. (1)	T _J = 25 °C	V Dated V	0.80	mA			
See fig. 2	I _{RM} ⁽¹⁾	T _J = 125 °C	V _R = Rated V _R	45				
Threshold voltage	V _{F(TO)}	T T mayimum		0.39	V			
Forward slope resistance	r _t	$T_J = T_J$ maximum	8.47	mΩ				
Maximum junction capacitance per leg	C _T	V _R = 5 V _{DC} (test signal ran	720	pF				
Typical series inductance per leg	L _S	Measured lead to lead 5 m	8.0	nH				
Maximum voltage rate of change	dV/dt	Rated V _R	10 000	V/µs				

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS					
Maximum junction and storage temperature range	T _J , T _{Stg}		-55 to +150	°C					
Maximum thermal resistance, junction to case per leg	В	DC operation	3.25						
Maximum thermal resistance, junction to case per package	- R _{thJC}	DC operation	1.63	°C/W					
Typical thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth and greased	0.50						
Approximate weight			2	g					
Approximate weight			0.07	oz.					
Mounting torque minimum			6 (5)	kgf · cm					
Mounting torque — maximum			12 (10)	(lbf \cdot in)					
Marking dayion		Coop otale 21 TO 220AP	30CTQ050						
Marking device		Case style 3L TO-220AB		Q060					

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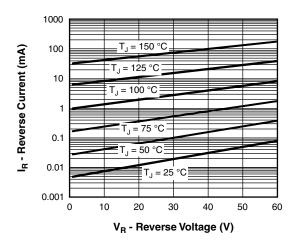


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

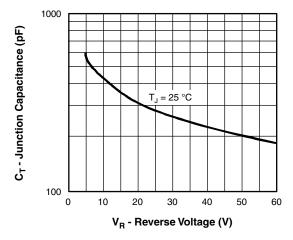


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

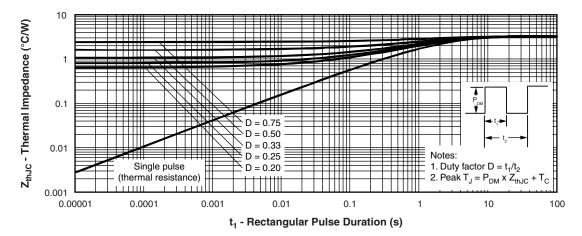


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)



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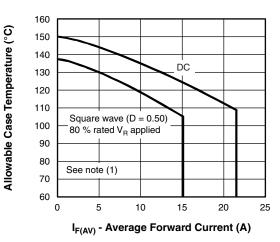


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

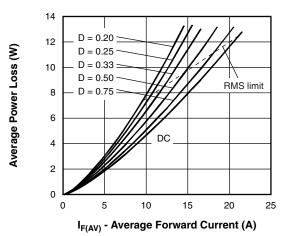


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

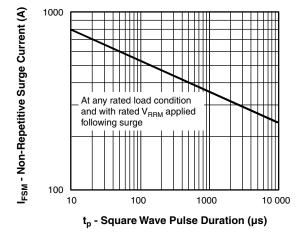


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

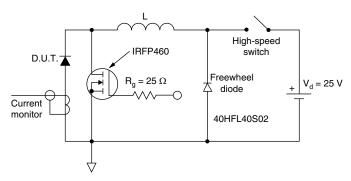


Fig. 8 - Unclamped Inductive Test Circuit

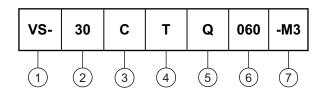
Note

 $^{(1)} \ \, \text{Formula used: } T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}; \\ Pd = \text{forward power loss} = I_{F(AV)} \times V_{FM} \text{ at } (I_{F(AV)}/D) \text{ (see fig. 6)}; \\ Pd_{REV} = \text{inverse power loss} = V_{R1} \times I_R \text{ (1 - D); } I_R \text{ at } V_{R1} = 10 \text{ V}$

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ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating (30 = 30 A)

Circuit configuration:

C = common cathode

4 - Package:

T = TO-220

5 - Schottky "Q" series

Voltage ratings — 050 = 50 V 060 = 60 V

7 - Environmental digit

-M3 = halogen-free, RoHS-compliant, and termination lead (Pb)-free

ORDERING INFORMATION (Example)									
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION						
VS-30CTQ050-M3	50	1000	Antistatic plastic tube						
VS-30CTQ060-M3	50	1000	Antistatic plastic tube						

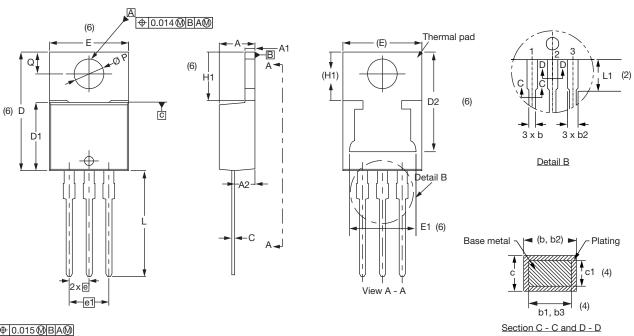
LINKS TO RELATED DOCUMENTS							
Dimensions <u>www.vishay.com/doc?96154</u>							
Part marking information	www.vishay.com/doc?95028						



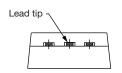
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3L TO-220AB

DIMENSIONS in millimeters and inches



⊕ 0.015 **M** B A **M**



Conforms to JEDEC® outline TO-220AB

SYMBOL	MILLIMETERS		INCHES		HES NOTES		SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES		STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.25	4.65	0.167	0.183			D2	11.68	13.30	0.460	0.524	6, 7
A1	1.14	1.40	0.045	0.055			E	10.11	10.51	0.398	0.414	3, 6
A2	2.50	2.92	0.098	0.115			E1	6.86	8.89	0.270	0.350	6
b	0.69	1.01	0.027	0.040			е	2.41	2.67	0.095	0.105	
b1	0.38	0.97	0.015	0.038	4		e1	4.88	5.28	0.192	0.208	
b2	1.20	1.73	0.047	0.068			H1	6.09	6.48	0.240	0.255	6
b3	1.14	1.73	0.045	0.068	4		L	13.52	14.02	0.532	0.552	
С	0.36	0.61	0.014	0.024			L1	3.32	3.82	0.131	0.150	2
c1	0.36	0.56	0.014	0.022	4		ØΡ	3.54	3.91	0.139	0.154	
D	14.85	15.35	0.585	0.604	3		Q	2.60	3.00	0.102	0.118	
D1	8.38	9.02	0.330	0.355		1		•			•	

Notes

- ⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3, and c1 apply to base metal only
- Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2, and E1
- (7) Outline conforms to JEDEC® TO-220, except D2



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